











ATL431LI-Q1 ATL432LI-Q1

SNVSBB0-MAY 2019

# ATL431LI-Q1 / ATL432LI-Q1 High Bandwidth Low-IQ Programmable Shunt Regulator

### 1 Features

- Qualified for automotive applications
- AEC-Q100 qualified with the following results:
  - Device temperature grade 1: -40°C to +125°C ambient operating temperature
- Reference voltage tolerance at 25°C
  - 0.5% (B Grade)
  - 1% (A Grade)
- Minimum typical output voltage: 2.5 V
- Adjustable output voltage: V<sub>ref</sub> to 36 V
- Operation from -40°C to +125°C
- 27 mV maximum temperature drift
- 0.65-Ω typical output impedance
- Sink-current capability
  - I<sub>min</sub> = 0.08 mA (max)
  - $I_{KA} = 15 \text{ mA (max)}$
- Reference input current I<sub>REF</sub>: 0.4 μA (max)
- Deviation of reference input current over temperature, I<sub>I(dev)</sub>: 0.3 μA (max)

# 2 Applications

- · Inverter and motor control
- DC/DC converter
- LED lighting
- On-board charger (OBC)
- · Infotainment and cluster

# 3 Description

ATL43xLI-Q1 device is a three-terminal adjustable shunt regulator, with specified thermal stability over applicable automotive, commercial, and military temperature ranges. The output voltage can be set to any value between V<sub>ref</sub> (approximately 2.5 V) and 36 V, with two external resistors. These devices have a typical output impedance of 0.65  $\Omega$ . Active output circuitry provides a very sharp turn-on characteristic, making these devices excellent replacements for Zener diodes in many applications, such as onboard regulation, adjustable power supplies, and switching power supplies. This device is a pin-to-pin alternative to the TL431LI-Q1 and TL432LI-Q1, with lower minimum operating current to help reduce system power consumption. The ATL432LI-Q1 device has exactly functionality and electrical specifications as the ATL431LI-Q1 device, but has a different pinout for the DBZ package.

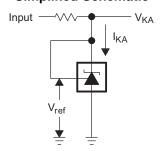
The ATL431LI-Q1 device is offered in two grades, with initial tolerances (at 25°C) of 0.5%, and 1%, for the B and A grade, respectively. In addition, low output drift versus temperature ensures good stability over the entire temperature range. The ATL43xLI-Q1 devices are characterized for operation from –40°C to +125°C.

# **Device Information**(1)

PART NUMBER	PACKAGE (PIN)	BODY SIZE (NOM)
ATL43xLI	SOT-23 (3)	2.90 mm x 1.30 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

# **Simplified Schematic**





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# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

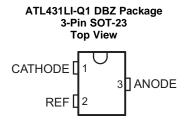
DATE	REVISION	NOTES
May 2019	* Initial re	

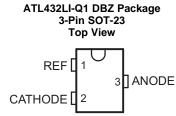


# 5 Device Comparison Table

DEVICE PINOUT	INITIAL ACCURACY	OPERATING FREE-AIR TEMPERATURE (T <sub>A</sub> )	
ATL431LI-Q1 ATL432LI-Q1	A: 1% B: 0.5%	Q: -40°C to 125°C	

# 6 Pin Configuration and Functions





# **Pin Functions**

	PIN	ı				
NAME	ATL431LI-Q1	ATL432LI-Q1	TYPE	DESCRIPTION		
	DBZ	DBZ				
ANODE	3	3	0	Common pin, normally connected to ground		
CATHODE	1	2	I/O	Shunt Current/Voltage input		
REF	2	1	I	Threshold relative to common anode		



# 7 Specifications

# 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
$V_{KA}$	Cathode Voltage (2)		37	٧
I <sub>KA</sub>	Continuos Cathode Current Range	-10	18	mA
I <sub>I(ref)</sub>	Reference Input Current	-5	10	mA
$T_{J}$	Operating Junction Temperature Range	-40	150	О
T <sub>stg</sub>	Storage Temperature Range	-65	150	С

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to ANODE, unless otherwise noted.

# 7.2 ESD Ratings

			VALUE	UNIT	
V	Electrostatic	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±4000	.,,	
V <sub>(ESD)</sub>	discharge	Charged-device model (CDM), per AEC Q100-011	±1000	V	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification

### 7.3 Thermal Information

		ATL43xLI	
	THERMAL METRIC <sup>(1)</sup>	DBZ	UNIT
		3 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	371.7	C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	145.9	C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	104.7	C/W
ΨЈТ	Junction-to-top characterization parameter	23.9	C/W
ΨЈВ	Juction-to-board characterization parameter	102.9	C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

# 7.4 Recommended Operating Conditions

See (1)

			MIN	MAX	UNIT
$V_{KA}$	Cathode Voltage				V
I <sub>KA</sub>	Continuous Cathode Current Range			15	mA
T <sub>A</sub>	Operating Free-Air Temperature	ATL43xLlxQ	-40	125	С

<sup>(1)</sup> Maximum power dissipation is a function of  $T_{J(max)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_{J(max)} - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.

#### 7.5 Eletrical Characteristics

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
\/	Deference Valtage	Coo Figure 47	\/ \/ \ \ \ 1 \ 1 \ m \lambda	ATL43xLIAx devices	2475	2500	2525	mV
$V_{REF}$	Reference Voltage	See Figure 17	$V_{KA} = V_{ref}$ , $I_{KA} = 1 \text{ mA}$	ATL43xLIBx devices	2487	2500	2512	mV



# **Eletrical Characteristics (continued)**

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN TYP	MAX	UNIT
V <sub>I(dev)</sub>	Deviation of reference input voltage over full temperature range (1)	See Figure 17	$V_{KA} = V_{ref}$ , $I_{KA} = 1$ mA	ATL43xLlxQ devices	10	27	mV
	Ratio of change in			$\Delta V_{KA} = 10 \text{ V} - V_{ref}$	-1.4	-2.7	mV/V
$\Delta V_{ref}$ / $\Delta V_{KA}$	reference voltage to the change in cathode voltage	See Figure 18	I <sub>KA</sub> = 1 mA	ΔV <sub>KA</sub> = 36 V - 10 V	-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 18	I <sub>KA</sub> = 1 mA, R1 = 10kΩ, R2 = ∞		0.2	0.4	μΑ
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 18	I <sub>KA</sub> = 1 mA, R1 = 10kΩ, R2 = ∞		0.1	0.3	μΑ
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 17	$V_{KA} = V_{ref}$		65	80	μΑ
I <sub>off</sub>	Off-state cathode current	See Figure 19	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0		0.1	1	μΑ
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 17	$V_{KA} = V_{ref}$ , $I_{KA} = 1$ mA to 15 mA		0.3	0.65	Ω

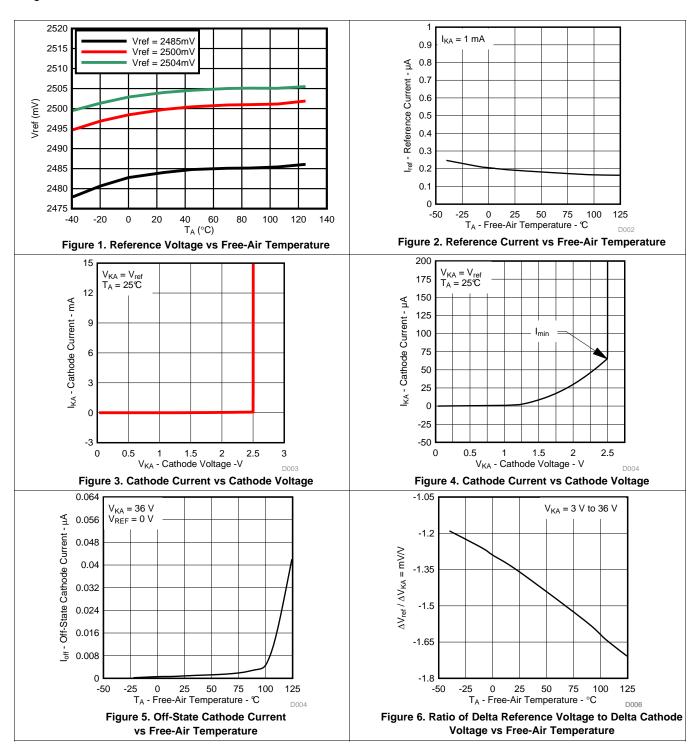
 $<sup>(1) \</sup>quad \text{The deviation parameters $V_{I(dev)}$ and $I_{I(dev)}$ are defined as the differences between the maximum and minimum values obtained over the $I_{I(dev)}$ and $I_{I(dev)}$ are defined as the differences between the maximum and minimum values obtained over the $I_{I(dev)}$ and $I_{I(dev)}$ are defined as the differences between the maximum and minimum values obtained over the $I_{I(dev)}$ and $I_{I(dev)}$ are defined as the differences between the maximum and minimum values obtained over the $I_{I(dev)}$ are defined as the differences between the maximum and minimum values obtained over the $I_{I(dev)}$ are defined as the differences between the maximum and minimum values obtained over the $I_{I(dev)}$ are defined as the differences between the maximum and minimum values obtained over the $I_{I(dev)}$ are defined as $I_{$ rated temperature range. For more details on  $V_{I(dev)}$  and how it relates to the average temperature coefficient, see Parameter Measurement Information.

The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{out}$ , see Parameter Measurement Information.



# 7.6 Typical Characteristics

Data at high and low temperatures are applicable only within the recommended operating free-air temperature ranges of the various devices.





# **Typical Characteristics (continued)**

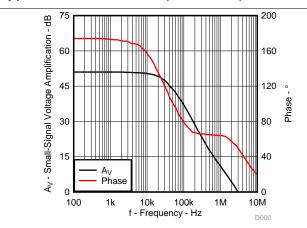


Figure 7. Small-Signal Voltage Amplification vs Frequency

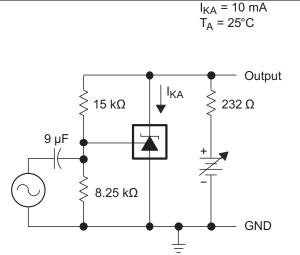


Figure 8. Test Circuit for Voltage Amplification

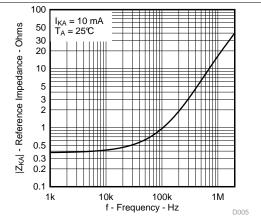


Figure 9. Reference Impedance vs Frequency

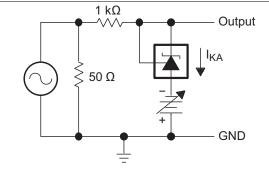
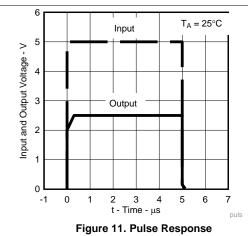


Figure 10. Test Circuit for Reference Impedance



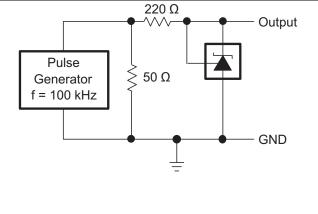
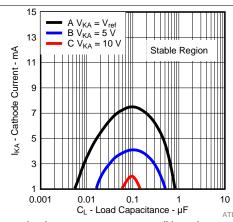


Figure 12. Test Circuit for Pulse Response

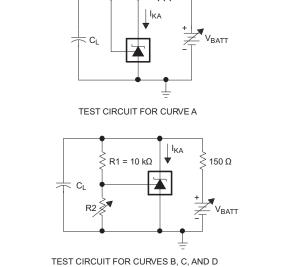


# **Typical Characteristics (continued)**



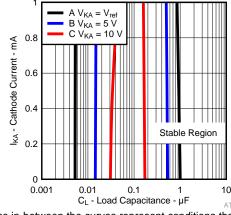
The areas under the curves represent conditions that may cause the device to oscillate. For curves B and C, R2 and V+ are adjusted to establish the initial  $V_{KA}$  and  $I_{KA}$  conditions, with  $C_L=0.\ V_{BATT}$  and  $C_L$  then are adjusted to determine the ranges of stability.

Figure 13. Stability Boundary Conditions for All ATL431-Q1, ATL432-Q1 Devices Above 1 mA



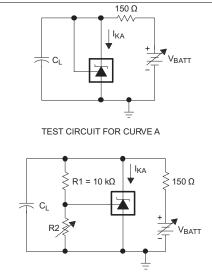
150 Ω

Figure 14. Test Circuit for Stability Boundary Conditions



The areas in-between the curves represent conditions that may cause the device to oscillate. For curves B, and C, R2 and V+ are adjusted to establish the initial  $V_{KA}$  and  $I_{KA}$  conditions, with  $C_L = 0$ .  $V_{BATT}$  and  $C_L$  then are adjusted to determine the ranges of stability.

Figure 15. Stability Boundary Conditions for All ATL431LI-Q1, ATL432LI-Q1 Devices Below 1 mA



TEST CIRCUIT FOR CURVES B, C, AND D

Figure 16. Test Circuit for Stability Boundary Conditions



# 8 Parameter Measurement Information

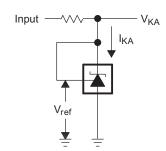


Figure 17. Test Circuit for  $V_{KA} = V_{ref}$ 

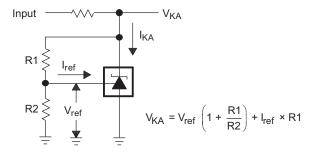


Figure 18. Test Circuit for  $V_{KA} > V_{ref}$ 

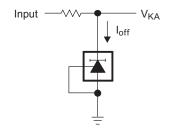


Figure 19. Test Circuit for Ioff

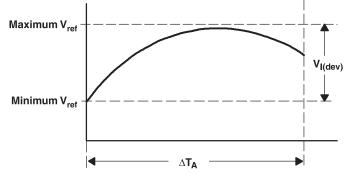
### 8.1 Temperature Coefficient

The deviation of the reference voltage,  $V_{ref}$ , over the full temperature range is known as  $V_{I(dev)}$ . The parameter of  $V_{I(dev)}$  can be used to find the temperature coefficient of the device. The average full-range temperature coefficient of the reference input voltage,  $\alpha_{Vref}$ , is defined as:

$$\left| \begin{array}{c} \alpha_{\text{vref}} \end{array} \right| \left( \frac{\text{ppm}}{^{\circ}\text{C}} \right) = \begin{array}{c} \left( \frac{V_{\text{I(dev)}}}{V_{\text{ref}} \text{ at 25}^{\circ}\text{C}} \right) \times 10^6 \\ \hline \Delta T_{\text{A}} \end{array}$$

where:

 $\Delta T_A$  is the rated operating temperature range of the device.



 $\alpha_{Vref}$  is positive or negative, depending on whether minimum  $V_{ref}$  or maximum  $V_{ref}$ , respectively, occurs at the lower temperature. The full-range temperature coefficient is an average and therefore any subsection of the rated operating temperature range can yield a value that is greater or less than the average. For more details on temperature coefficient, check out *Voltage Reference Selection Basics*.



# 8.2 Dynamic Impedance

The dynamic impedance is defined as:  $|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_{KA}}$  . When the device is operating with two external resistors  $|z'| = \frac{\Delta V}{\Delta I_{KA}}$ 

(see Figure 18), the total dynamic impedance of the circuit is given by:  $|z| = \frac{1}{\Delta I}$  which is approximately equal to  $|Z_{KA}| \left(1 + \frac{R1}{R2}\right)$ 

The  $V_{KA}$  of the ATL431LI-Q1 can be affected by the dynamic impedance. The ATL431LI-Q1 test current  $I_{test}$  for  $V_{KA}$  is specified on the *Eletrical Characteristics*. Any deviation from  $I_{test}$  can cause deviation on the output  $V_{KA}$ . Figure 20 shows the effect of the dynamic impedance on the  $V_{KA}$ .

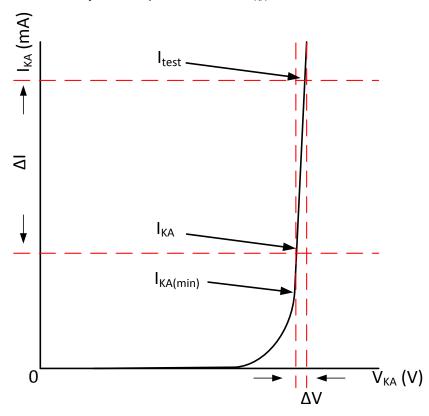


Figure 20. Dynamic Impedance



# 9 Detailed Description

#### 9.1 Overview

This standard device has proven ubiquity and versatility across a wide range of applications, ranging from power to signal path. This is due to its key components containing an accurate voltage reference and opamp, which are very fundamental analog building blocks. ATL431LI-Q1 is used in conjunction with it's key components to behave as a single voltage reference, error amplifier, voltage clamp or comparator with integrated reference.

ATL431LI-Q1 can be operated and adjusted to cathode voltages from 2.5V to 36V, making this part optimum for a wide range of end equipments in industrial, auto, telecom & computing. In order for this device to behave as a shunt regulator or error amplifier, >100 $\mu$ A (I<sub>min</sub>(maximum)) must be supplied in to the cathode pin. Under this condition, feedback can be applied from the Cathode and Ref pins to create a replica of the internal reference voltage.

Various reference voltage options can be purchased with initial tolerances (at 25°C) of 0.5%, and 1%. These reference options are denoted by B (0.5%) and A (1.0%) after the ATL431LI-Q1 or ATL432LI-Q1. ATL431LI-Q1 and ATL432LI-Q1 are both functionally the same, but have separate pinout options. The ATL43xLI-Q1 devices are characterized for operation from -40°C to +125°C.

# 9.2 Functional Block Diagram

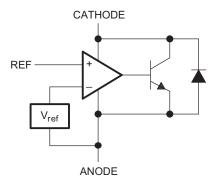


Figure 21. Equivalent Schematic

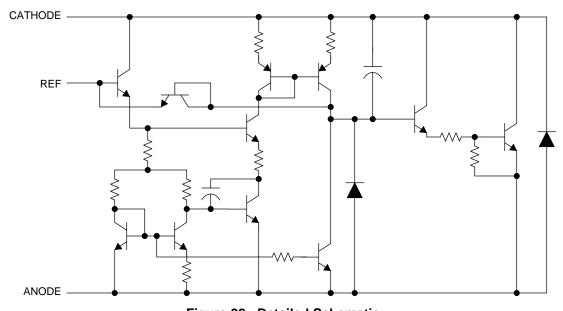


Figure 22. Detailed Schematic



### 9.3 Feature Description

ATL431LI-Q1 consists of an internal reference and amplifier that outputs a sink current based on the difference between the reference pin and the virtual internal pin. The sink current is produced by the internal Darlington pair, shown in the above schematic (Figure 21). A Darlington pair is used in order for this device to be able to sink a maximum current of 15 mA.

When operated with enough voltage headroom ( $\geq 2.5$  V) and cathode current ( $I_{KA}$ ), ATL431LI-Q1 forces the reference pin to 2.5 V. However, the reference pin can not be left floating, as it needs  $I_{REF} \geq 0.4~\mu A$  ( see *Specifications*). This is because the reference pin is driven into an NPN, which needs base current in order operate properly.

When feedback is applied from the Cathode and Reference pins, ATL431LI-Q1 behaves as a Zener diode, regulating to a constant voltage dependent on current being supplied into the cathode. This is due to the internal amplifier and reference entering the proper operating regions. The same amount of current needed in the above feedback situation must be applied to this device in open loop, servo or error amplifying implementations in order for it to be in the proper linear region giving ATL431LI-Q1 enough gain.

Unlike many linear regulators, ATL431LI-Q1 is internally compensated to be stable without an output capacitor between the cathode and anode. However, if it is desired to use an output capacitor Figure 13 can be used as a guide to assist in choosing the correct capacitor to maintain stability.

### 9.4 Device Functional Modes

# 9.4.1 Open Loop (Comparator)

When the cathode/output voltage or current of ATL431LI-Q1 is not being fed back to the reference/input pin in any form, this device is operating in open loop. With proper cathode current (Ika) applied to this device, ATL431LI-Q1 will have the characteristics shown in Figure 21. With such high gain in this configuration, ATL431LI-Q1 is typically used as a comparator. With the reference integrated makes ATL431LI-Q1 the preferred choice when users are trying to monitor a certain level of a single signal.

### 9.4.2 Closed Loop

When the cathode/output voltage or current of ATL431LI-Q1 is being fed back to the reference/input pin in any form, this device is operating in closed loop. The majority of applications involving ATL431LI-Q1 use it in this manner to regulate a fixed voltage or current. The feedback enables this device to behave as an error amplifier, computing a portion of the output voltage and adjusting it to maintain the desired regulation. This is done by relating the output voltage back to the reference pin in a manner to make it equal to the internal reference voltage, which can be accomplished via resistive or direct feedback.



# 10 Applications and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 10.1 Application Information

As this device has many applications and setups, there are many situations that this datasheet can not characterize in detail. The linked application notes will help the designer make the best choices when using this part.

Application note *Understanding Stability Boundary Conditions Charts in TL431, TL432 Data Sheet,* SLVA482 provides a deeper understanding of this device's stability characteristics and aid the user in making the right choices when choosing a load capacitor. Application note *Setting the Shunt Voltage on an Adjustable Shunt Regulator,* SLVA445 assists with setting the shunt voltage to achieve optimum accuracy for this device.

# 10.2 Typical Applications

### 10.2.1 Comparator With Integrated Reference

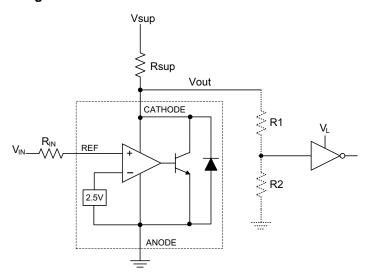


Figure 23. Comparator Application Schematic



# **Typical Applications (continued)**

### 10.2.1.1 Design Requirements

For this design example, use the parameters listed in *Table 1* as the input parameters.

**Table 1. Design Parameters** 

DESIGN PARAMETER	EXAMPLE VALUE
Input Voltage Range	0 V to 5 V
Input Resistance	10 kΩ
Supply Voltage	24 V
Cathode Current (lk)	5 mA
Output Voltage Level	~2 V – V <sub>SUP</sub>
Logic Input Thresholds VIH/VIL	$V_L$

#### 10.2.1.2 Detailed Design Procedure

When using ATL431LI-Q1 as a comparator with reference, determine the following:

- Input Voltage Range
- Reference Voltage Accuracy
- · Output logic input high and low level thresholds
- · Current Source resistance

### 10.2.1.2.1 Basic Operation

In the configuration shown in Figure 23 ATL431LI-Q1 will behave as a comparator, comparing the  $V_{REF}$  pin voltage to the internal virtual reference voltage. When provided a proper cathode current ( $I_K$ ), ATL431LI-Q1 will have enough open loop gain to provide a quick response. This can be seen in Figure 24, where the  $R_{SUP}$ =10 k $\Omega$  ( $I_{KA}$ =500  $\mu$ A) situation responds much slower than  $R_{SUP}$ =1 k $\Omega$  ( $I_{KA}$ =5 mA). With the ATL431LI-Q1 max Operating Current ( $I_{MIN}$ ) being 1 mA, operation below that could result in low gain, leading to a slow response.

# 10.2.1.2.1.1 Overdrive

Slow or inaccurate responses can also occur when the reference pin is not provided enough overdrive voltage. This is the amount of voltage that is higher than the internal virtual reference. The internal virtual reference voltage will be within the range of  $2.5 \text{ V} \pm (0.5\% \text{ or } 1.0\%)$  depending on which version is being used. The more overdrive voltage provided, the faster the ATL431LI-Q1 will respond.

For applications where ATL431LI-Q1 is being used as a comparator, it is best to set the trip point to greater than the positive expected error (that is  $\pm 1.0\%$  for the A version). For fast response, setting the trip point to  $\pm 1.0\%$  of the internal  $\pm 1.0\%$  of the int

For minimal voltage drop or difference from Vin to the ref pin, TI recommends to use an input resistor <10k $\Omega$  to provide Iref.



#### 10.2.1.2.2 Output Voltage and Logic Input Level

In order for ATL431LI-Q1 to properly be used as a comparator, the logic output must be readable by the receiving logic device. This is accomplished by knowing the input high and low level threshold voltage levels, typically denoted by  $V_{IH}$  and  $V_{II}$ .

As seen in Figure 24, ATL431LI-Q1's output low level voltage in open-loop/comparator mode is approximately 2 V, which is typically sufficient for 5V supplied logic. However, would not work for 3.3 V and 1.8 V supplied logic. To accommodate this a resistive divider can be tied to the output to attenuate the output voltage to a voltage legible to the receiving low voltage logic device.

ATL431's output high voltage is equal to  $V_{SUP}$  due to ATL431LI-Q1 being open-collector. If  $V_{SUP}$  is much higher than the receiving logic's maximum input voltage tolerance, the output must be attenuated to accommodate the outgoing logic's reliability.

When using a resistive divider on the output, be sure to make the sum of the resistive divider (R1 and R2 in Figure 23) is much greater than  $R_{SUP}$  in order to not interfere with ATL431LI-Q1's ability to pull close to  $V_{SUP}$  when turning off.

#### 10.2.1.2.2.1 Input Resistance

ATL431LI-Q1 requires an input resistance in this application in order to source the reference current ( $I_{REF}$ ) needed from this device to be in the proper operating regions while turning on. The actual voltage seen at the ref pin will be  $V_{REF}=V_{IN}-I_{REF}*R_{IN}$ . Because  $I_{REF}$  can be as high as 4  $\mu$ A. TI recommends to use a resistance small enough that will mitigate the error that  $I_{REF}$  creates from  $V_{IN}$ .

### 10.2.1.3 Application Curve

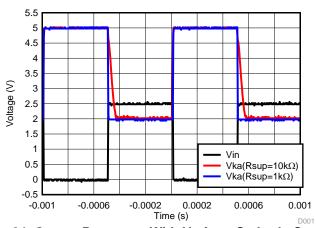


Figure 24. Output Response With Various Cathode Currents



### 10.2.2 Precision LED Lighting Current Sink Regulator

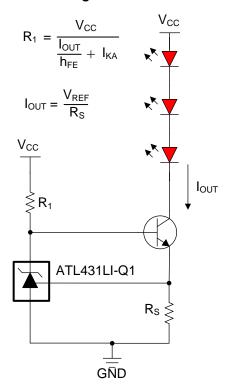


Figure 25. LED Lighting Current Sink Regulator

#### 10.2.2.1 Design Requirements

For this design example, use the parameters listed in *Table 1* as the input parameters.

**Table 2. Design Parameters** 

DESIGN PARAMETER	EXAMPLE VALUE
Supply Voltage (V <sub>I(BATT)</sub> )	5 V
Sink Current (I <sub>O</sub> )	100mA
Cathode Current (lk)	5 mA

### 10.2.2.2 Detailed Design Procedure

When using ATL43xLI-Q1 as a constant current sink, determine the following:

- Output Current Range
- Output Current Accuracy
- Power Consumption for ATL43xLI

### 10.2.2.2.1 Basic Operation

In the configuration shown, ATL43xLI-Q1 acts as a control component within a feedback loop of the constant current sink. Working with an external passing component such as an BJT, ATL43xLI-Q1 provides precision current sink with accuracy set by itself and the sense resistor R<sub>S</sub>. The LEDs are lit based on the desired current sink and regulated for accurate brightness and color.

### 10.2.2.2.1.1 Output Current Range and Accuracy

The output current range of the circuit is determined by the equation shown in the configuration. Keep in mind that the  $V_{REF}$  equals to 2.500 V. When choosing the sense resistor  $R_S$ , it needs to generate 2.500 V for the TL43xLI-Q1 when  $I_O$  reaches the target current. If the overhead voltage of 2.500 V is not acceptable, please consider lower voltage reference devices such as TLV43x-Q1 or TLVH43x-Q1.



The output current accuracy is determined by both the accuracy of ATL43xLI-Q1 chosen, as well as the accuracy of the sense resistor  $R_S$ . The internal virtual reference voltage of ATL43xLI-Q1 will be within the range of 2.500 V  $\pm$ (0.5% or 1.0%) depending on which version is being used. Another consideration for the output current accuracy is the temperature coefficient of the ATL43xLI-Q1 and  $R_S$ . Please refer to the electrical characterization table for the specification of these parameters.

#### 10.2.2.2.2 Power Consumption

In order for ATL43xLI-Q1 to properly be used as a control component in this circuit, the minimum operating current needs to be reached. This is accomplished by setting the external biasing resistor in series with the ATL43xLI-Q1.

To achieve lower power consumption the ATL43xLI-Q1 is used due to its 65  $\mu A$  typical minimum cathode current,  $I_{min}$ .

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### 10.2.3 Shunt Regulator/Reference

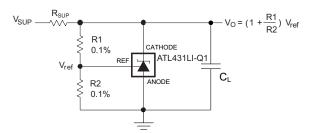


Figure 26. Shunt Regulator Schematic

### 10.2.3.1 Design Requirements

For this design example, use the parameters listed in Table 1 as the input parameters.

DESIGN PARAMETEREXAMPLE VALUEReference Initial Accuracy1.0%Supply Voltage24 VCathode Current (Ik)5 mAOutput Voltage Level2.5 V - 36 VLoad Capacitance2 µF

**Table 3. Design Parameters** 

# 10.2.3.2 Detailed Design Procedure

When using ATL431LI-Q1 as a Shunt Regulator, determine the following:

Feedback Resistor Values and Accuracy (R1 and R2)

- Input Voltage Range
- Temperature Range
- Total Accuracy
- Cathode Current
- Reference Initial Accuracy
- Output Capacitance

#### 10.2.3.2.1 Programming Output/Cathode Voltage

In order to program the cathode voltage to a regulated voltage a resistive bridge must be shunted between the cathode and anode pins with the mid point tied to the reference pin. This can be seen in Figure 26, with R1 and R2 being the resistive bridge. The cathode/output voltage in the shunt regulator configuration can be approximated by the equation shown in Figure 26. The cathode voltage can be more accuratel determined by taking in to account the cathode current:

$$Vo = (1+R1/R2) \times V_{REF} - I_{REF} \times R1$$
 (1)

In order for this equation to be valid, ATL431LI-Q1 must be fully biased so that it has enough open loop gain to mitigate any gain error. This can be done by meeting the Imin spec denoted in *Specifications*.

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10  $k\Omega$ 



#### 10.2.3.2.2 Total Accuracy

When programming the output above unity gain ( $V_{KA}=V_{REF}$ ), ATL431LI-Q1 is susceptible to other errors that may effect the overall accuracy beyond  $V_{RFF}$ . These errors include:

- R1 and R2 accuracies
- V<sub>I(dev)</sub> Change in reference voltage over temperature
- $\Delta V_{REF}$  /  $\Delta V_{KA}$  Change in reference voltage to the change in cathode voltage

Worst case cathode voltage can be determined taking all of the variables in to account. Application note *Setting the Shunt Voltage on an Adjustable Shunt Regulator*, SLVA445 assists designers in setting the shunt voltage to achieve optimum accuracy for this device.

### 10.2.3.2.3 Stability

Though ATL431LI-Q1 is stable with no capacitive load, the device that receives the shunt regulator's output voltage could present a capacitive load that is within the ATL431LI-Q1 region of stability, shown in Figure 13. Also, designers may use capacitive loads to improve the transient response or for power supply decoupling. When using additional capacitance between Cathode and Anode, see Figure 13. Also, application note *Understanding Stability Boundary Conditions Charts in TL431, TL432 Data Sheet*, SLVA482 will provide a deeper understanding of this devices stability characteristics and aid the user in making the right choices when choosing a load capacitor.

# 10.2.3.2.4 Start-Up Time

As shown in Figure 27, ATL431LI-Q1 has a fast response up to approximately 2 V and then slowly charges to its programmed value. This is due to the compensation capacitance (shown in Figure 13) the ATL43xLI-Q1 has to meet its stability criteria. Despite the secondary delay, ATL43xLI-Q1 still has a fast response suitable for many clamp applications.

### 10.2.3.3 Application Curve

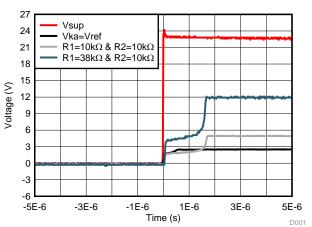


Figure 27. ATL43xLI-Q1 Start-Up Response

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### 10.2.4 Isolated Flyback with Optocoupler

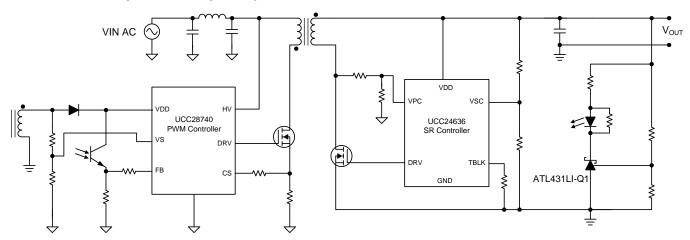


Figure 28. Isolated Flyback with Optocoupler

# 10.2.4.1 Design Requirements

The ATL431LI-Q1 is used in the feedback network on the secondary side for a isolated flyback with optocoupler design. Figure 28 shows the simplified flyback converter that used the ATL431LI-Q1. For this design example, use the parameters in Table 4 as the input parameters.

**Table 4. Design Parameters** 

DESIGN PARAMETER	EXAMPLE VALUE				
Voltage Output	20 V				
Feedback Network Quiescent Current (I <sub>q</sub> )	<40 mW				

#### 10.2.4.1.1 Detailed Design Procedure

In this example a simplified design procedure will be discussed. The compensation network for the feedback network is beyond the scope of this section. Details on compensation network can be found on SLUA671.

The goal of this design is to design a low standby current feedback network to meet the Europe CoC Tier 2 and United States DoE Level VI requirements. To meet the design requirements, the system standby power needs to be below 75mW. In order to meet this, the feedback network needs to consume less than 40mW to allow margin for the power losses on the primary side controller and passive components and this can pose a challenge in systems greater than 10V.

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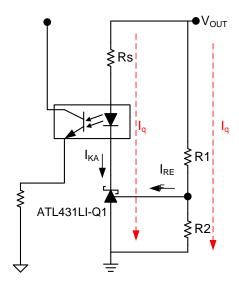


Figure 29. Feedback Quiescent Current

#### 10.2.4.1.1.1 ATL431LI-Q1 Biasing

Figure 29 shows the simplified version of the feedback network. The standby  $I_q$  of the system is dependent on two paths, ATL431LI-Q1 biasing path and the resistor feedback path. With the given design requirements the total current through the feedback network cannot exceed 2mA.

The design goal is to take full advantage of the  $I_{min}$  to set the  $I_{KA}$  of the ATL431LI-Q1. The benefit of the ATL431LI-Q1 is its low  $I_{min}$  of 80  $\mu$ A which allows the  $I_{KA}$  to be lower at a full load condition compared to typical TL431LI-Q1 devices. This helps lower the  $I_{KA}$  at the no-load condition which is higher than the full load condition due to the dynamic changes in the  $I_{KA}$  as the system load varies. The  $I_{KA}$  at no-load,  $I_{OPTNL}$ , is dependent the value of Rs which is the biasing resistor. Rs is very application specific and is dependent on variables such as optocoupler's CTR, voltage, and current at no-load and this can be seen on Equation 2. By using an optocoupler with a high CTR it is possible to lower  $I_{OPTNL}$  to a value of 1.5 mA for a power loss of 30 mW.

$$Rs \approx (V_{OUT} - V_{OPTNL} - 2V) / I_{OPTNL}$$

V<sub>OPTNI</sub> = Optocoupler Voltage at No – Load Conditions

#### 10.2.4.1.1.2 Resistor Feedback Network

The feedback resistors set the output voltage of the secondary side and will consume the same  $I_q$  at a fixed voltage. The design goal for the feedback resistor path is to minimize the resistor error while maintaining a low  $I_q$ . For this system example the feedback network path in this design will consume 0.5 mA to allow enough current for ATL431LI-Q1 biasing. The resistors, R1 and R2, are sized based on a 0.5 mA budget for  $I_q$  and  $I_{ref}$ . By using the resistor values from Equation 3 and Equation 4 the total power consumption will be 10mW and this can be further decreased by using larger resistors.

$$R_1 = (V_{OUT} - V_{REF}) / I_{FB}$$

$$R_1 = (20 \text{ V} - 2.5 \text{ V}) / 0.5 \text{ mA}$$

$$R_1 = 35 k\Omega \tag{3}$$

$$R_2 = V_{REF} / (I_{FB} - I_{REF})$$

$$R_2 = 2.5 \, \text{V} / (0.5 \, \text{mA} - 0.4 \, \mu \text{A})$$

$$R_2 = 5.004 \, k\Omega \tag{4}$$



### 10.2.5 Adjustable LDO Reference

### 10.2.5.1 Design Requirements

The ATL431LI-Q1 is used as a reference voltage to help regulate a supply voltage off an LDO. By adjusting the cathode voltage, the output voltage of the LDO can vary. The TPS7B4250-Q1 is a voltage-tracking LDO with an adjustable pin which needs a precise reference voltage to to change the regulate output voltage.

Table :	5. Des	ign Paı	rameters
---------	--------	---------	----------

DESIGN PARAMETER	EXAMPLE VALUE
Input Voltage	4 V to 40 V
ADJ Reference Voltage	2.500 V - 18 V
Output Voltage	2.500 V - 18 V
Output Current Rating	50 mA
Output Capacitor Range	1 μF to 50 μF
Output Capacitor ESR Range	1 m $\Omega$ to 20 $\Omega$

### 10.2.5.1.1 Detailed Design Procedure

The goal of this design to create a precision and stable output stage using an LDO that requires an external voltage reference such as the TPS7B4250-Q1. To begin the design process, the input and desired output voltage range is required. The ATL431LI-Q1 can be adjusted between 2.5 V and 36V so it covers most of the output voltage rating of TPS7B42500-Q1. For reference voltage under 2.5V, the TLV431-Q1 voltage reference can be used. The input and output capacitor must also be taken into consideration for decoupling and stability.

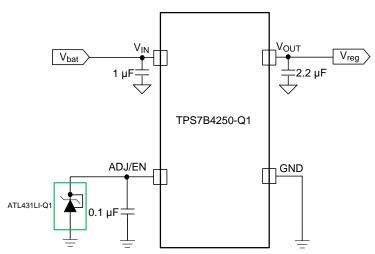


Figure 30. Feedback Quiescent Current

#### 10.2.5.1.1.1 External Capacitors

An input capacitor, CI, is recommended to buffer line influences. Connect the capacitors close to the IC pins.

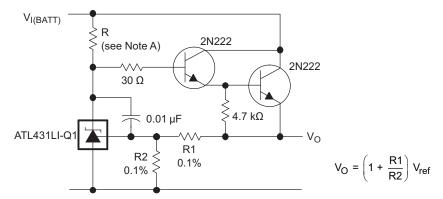
The output capacitor for the TPS7B4250-Q1 device is required for stability. Without the output capacitor, the regulator oscillates. The actual size and type of the output capacitor can vary based on the application load and temperature range. The effective series resistance (ESR) of the capacitor is also a factor in the IC stability. The worst case is determined at the minimum ambient temperature and maximum load expected. To ensure stability of TPS7B4250-Q1 device, the device requires an output capacitor between 1  $\mu$ F and 50  $\mu$ F with an ESR range between 0.001  $\Omega$  and 20  $\Omega$  that can cover most types of capacitor ESR variation under the recommend operating conditions. As a result, the output capacitor selection is flexible.

The capacitor must also be rated at all ambient temperature expected in the system. To maintain regulator stability down to -40°C, use a capacitor rated at that temperature.

22 Submi



# 10.3 System Examples



A. R should provide cathode current  $\geq$  0.1 mA to the ATL431LI-Q1 at minimum  $V_{(BATT)}$ .

Figure 31. Precision High-Current Series Regulator

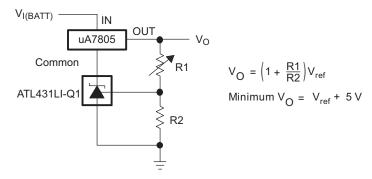


Figure 32. Output Control of a Three-Terminal Fixed Regulator

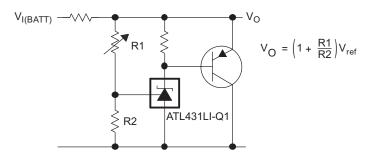
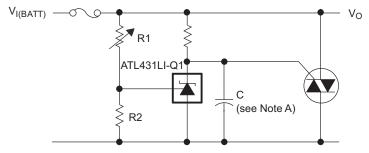


Figure 33. High-Current Shunt Regulator



A. Refer to the stability boundary conditions in and Figure 13 to determine allowable values for C.

Figure 34. Crowbar Circuit

# **System Examples (continued)**

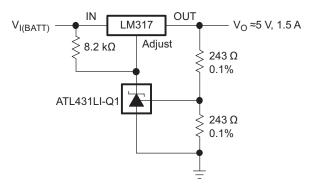
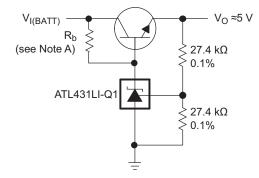


Figure 35. Precision 5-V, 1.5-A Regulator



A. R<sub>b</sub> should provide cathode current ≥1 mA to the ATL431LI-Q1.

Figure 36. Efficient 5-V Precision Regulator

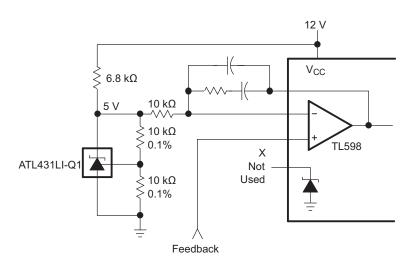
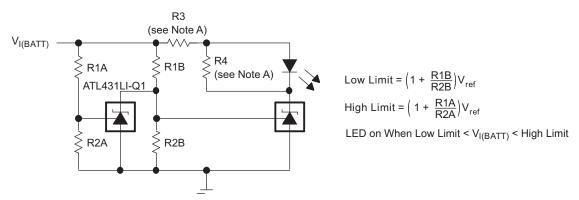


Figure 37. PWM Converter With Reference

**ADVANCE INFORMATION** 



# System Examples (continued)



A. Select R3 and R4 to provide the desired LED intensity and cathode current ≥ 0.1 mA to the ATL431LI-Q1 at the available V<sub>I(BATT)</sub>.

Figure 38. Voltage Monitor

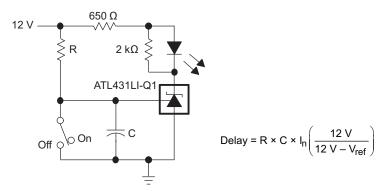


Figure 39. Delay Timer

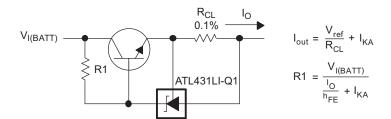


Figure 40. Precision Current Limiter

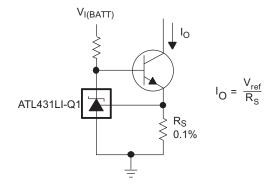


Figure 41. Precision Constant-Current Sink



# 11 Power Supply Recommendations

When using ATL43xLI-Q1 as a Linear Regulator to supply a load, designers will typically use a bypass capacitor on the output/cathode pin. When doing this, be sure that the capacitance is within the stability criteria shown in Figure 13.

To not exceed the maximum cathode current, be sure that the supply voltage is current limited. Also, be sure to limit the current being driven into the Ref pin, as not to exceed its absolute maximum rating.

For applications shunting high currents, pay attention to the cathode and anode trace lengths, adjusting the width of the traces to have the proper current density.

# 12 Layout

## 12.1 Layout Guidelines

Bypass capacitors should be placed as close to the part as possible. Current-carrying traces need to have widths appropriate for the amount of current they are carrying; in the case of the ATL43xLI-Q1, these currents will be low.

# 12.2 Layout Example

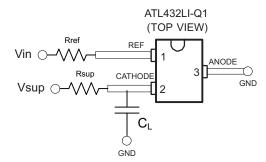


Figure 42. DBZ Layout Example

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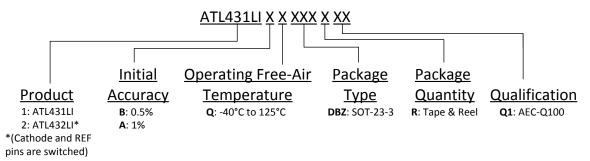


# 13 Device and Documentation Support

# 13.1 Documentation Support

#### 13.1.1 Device Nomenclature

TI assigns suffixes and prefixes to differentiate all the combinations of the ATL43xLI-Q1 family. More details and possible orderable combinations are located in the Package Option Addendum.



#### 13.1.2 Related Documentation

For related documentation see the following:

- Understanding Stability Boundary Conditions Charts in TL431, TL432 Data Sheet, SLVA482
- Setting the Shunt Voltage on an Adjustable Shunt Regulator, SLVA445

#### 13.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 6. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
ATL431LI-Q1	Click here	Click here	Click here	Click here	Click here
ATL432LI-Q1	Click here	Click here	Click here	Click here	Click here

#### 13.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 13.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Product Folder Links: ATL431LI-Q1 ATL432LI-Q1

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 13.5 Trademarks

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# 13.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

# 13.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

ADVANCE INFORMATION





6-Nov-2019

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
ATL431LIAQDBZRQ1	PREVIEW	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	22XP	
ATL431LIBQDBZRQ1	PREVIEW	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	22ZP	
ATL432LIAQDBZRQ1	PREVIEW	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	23AP	
ATL432LIBQDBZRQ1	PREVIEW	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	23BP	
PATL431LIAQDBZRQ1	ACTIVE	SOT-23	DBZ	3	3000	TBD	Call TI	Call TI	-40 to 125		Samples
PATL431LIBQDBZRQ1	ACTIVE	SOT-23	DBZ	3	3000	TBD	Call TI	Call TI	-40 to 125		Samples
PATL432LIAQDBZRQ1	ACTIVE	SOT-23	DBZ	3	3000	TBD	Call TI	Call TI	-40 to 125		Samples
PATL432LIBQDBZRQ1	ACTIVE	SOT-23	DBZ	3	3000	TBD	Call TI	Call TI	-40 to 125		Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



# **PACKAGE OPTION ADDENDUM**

6-Nov-2019

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF ATL431LI-Q1, ATL432LI-Q1:

Catalog: ATL431LI, ATL432LI

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4203227/C





SMALL OUTLINE TRANSISTOR



# NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   Reference JEDEC registration TO-236, except minimum foot length.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



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